

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q79703

Hisayuki MIKI, et al.

Appln. No.: 10/586,849

Group Art Unit: 2814

Confirmation No.: 3462

Examiner: Thoa X. Le

Filed: July 20, 2006

For: GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR MULTILAYER
STRUCTURE AND PRODUCTION METHOD THEREOF

RESPONSE TO RESTRICTION REQUIREMENT

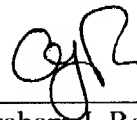
Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Responsive to the outstanding Restriction Requirement of September 13, 2007, Applicant elects Group I, claims 1-23 (drawn to a gallium nitride compound structure), for prosecution, without traverse. Applicant reserves the right to request rejoinder of method claims including all the limitations of any allowable product claim pursuant to MPEP §821.04. Applicant also reserves the right to file a Divisional Application directed to the non-elected subject matter.

The USPTO is directed and authorized to charge all required fees, except for the Issue Fee and the Publication Fee, to Deposit Account No. 19-4880. Please also credit any overpayments to said Deposit Account.

Respectfully submitted,



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CUSTOMER NUMBER

Date: September 27, 2007